

Exam Summer Semester 2022

Student Group

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Table of Contents

Exam Summer Semester 2022	2
Additional permitted Aids	2
Hits	2
Only EEE1-relevant Part	2
Exercise E2 Electrostatics I (written test, approx. 10 % of a 120-minute written test, SS2022)	2
Exercise E4 Electrostatics II (written test, approx. 10 % of a 120-minute written test, SS2022)	4
Exercise E8 Capacitor (written test, approx. 7 % of a 120-minute written test, SS2022)	4
Exercise E10 Magnetic Circuit (written test, approx. 7 % of a 120-minute written test, SS2022)	6
Full Exam	7
Exercise E2 Electrostatics I (written test, approx. 10 % of a 120-minute written test, SS2022)	7
Exercise E4 Electrostatics II (written test, approx. 10 % of a 120-minute written test, SS2022)	9
Exercise E6 Electron Velocity in Semiconductors (written test, approx. 6 % of a 120-minute written test, SS2022)	10
Exercise E8 Capacitor (written test, approx. 7 % of a 120-minute written test, SS2022)	10
Exercise E10 Magnetic Circuit (written test, approx. 7 % of a 120-minute written test, SS2022)	12
Exercise E11 Self Induction (written test, approx. 8 % of a 120-minute written test, SS2022)	13
Exercise E13 Series Resonant Circuit (written test, approx. 10 % of a 120-minute written test, SS2022)	14

Exam Summer Semester 2022

Additional permitted Aids

- non-programmable calculator,
- formulary (4 one-sided DIN A4 pages)

Hits

- The duration of the exam is 120 min.
- Attempts to cheat will lead to exclusion and failure of the exam.
- Withdrawal is no longer possible after these exam has been handed out.
- Please write down intermediate calculations and results on the assignment sheet. (when more space is needed also on the reverse side. In this case: Mark it clearly).
- Always use units in the calculation.
- Use a document-proof, non-red pen.

Only EEE1-relevant Part

This part is only for about 40 minutes !

Exercise E2 Electrostatics I

(written test, approx. 10 % of a 120-minute written test, SS2022)

2. Which net charge must be placed on the ring to get the picture below? The value of the previous result is E_4 . Which value needs E_4 to have to get a resulting force of $0 \text{ ~}\mu\text{N}$ on q_0 ?

Path: $q_0 = -1 \text{ ~nC}$

- $q_1 = -2 \text{ ~nC}$

Path: $E_4 = 4310.97 \text{ ~V/m}$ over $\{\text{rm m}\}$

$$\vec{F}_1 = \left(\begin{array}{c} 19.97 \cdot 10^{-6} \text{ ~N} \\ 0 \end{array} \right)$$

In the beginning, the are 5 components, we can not calculate the resulting magnitude of the force with the superposition theorem, we have to use the Pythagorean theorem.

$$F = \sqrt{F_1^2 + F_2^2} = \sqrt{(19.97 \cdot 10^{-6})^2 + (8.854 \cdot 10^{-6})^2} = 2.19 \cdot 10^{-5} \text{ ~N}$$

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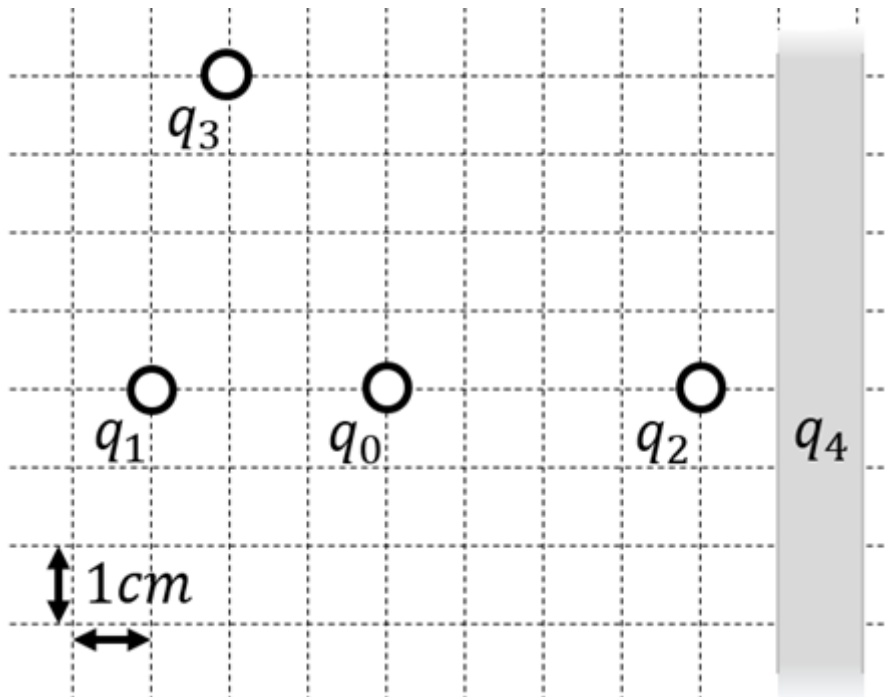
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1. Calculate the single forces $\vec{F}_{01}$, $\vec{F}_{02}$, $\vec{F}_{03}$, on the charge q_0 !

Path

First, calculate the magnitude of the forces, like $\vec{F}_{01}$.

The force $\vec{F}_{01}$ is purely on the x -axis and therefore equal to

$$\begin{aligned} F_{01,x} &= \frac{1}{4\pi\epsilon_0} \cdot \frac{q_1 \cdot q_0}{r_{01}^2} = \\ &= \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ As/Vm}} \cdot \frac{1 \cdot 10^{-9} \text{ C} \cdot 2 \cdot 10^{-9} \text{ C}}{(3 \cdot 10^{-2} \text{ m})^2} = 19.97... \cdot 10^{-6} \text{ Nm} \\ &= 19.97... \cdot 10^{-6} \text{ Nm} \quad \text{(to the right)} \end{aligned}$$

Similarly, we get for $\vec{F}_{02}$ and $\vec{F}_{03}$

$$\begin{aligned} \vec{F}_{02} &= F_{02,x} = -28.09... \text{ Nm} \quad \text{(to the right)} \\ \vec{F}_{03} &= -22.47... \text{ Nm} \quad \text{(to the top left)} \end{aligned}$$

For $\vec{F}_{03}$, we have to calculate the x - and y -component.

This is possible, by using the angle α between the line through q_0 and q_3 and the positive x -axis (pointing to the right).

So, α has to be between 90° and 180° . It can be calculated by:

$$\begin{aligned} \alpha &= \arctan\left(\frac{-4 \text{ cm}}{+2 \text{ cm}}\right) = \pi - 1.1071... \\ &= 180^\circ - 63.4...^\circ = 116.6...^\circ \end{aligned}$$

Based on this, the x - and y -component is:

$$\begin{aligned} |\vec{F}_{03}| \cdot \cos \alpha &= 10.05... \text{ Nm} \quad \text{(to the left)} \\ F_{03,y} &= |\vec{F}_{03}| \cdot \sin \alpha = 20.10... \text{ Nm} \quad \text{(to the top)} \end{aligned}$$

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top)} \end{align*}
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Exercise E4 Electrostatics II

(written test, approx. 10 % of a 120-minute written test, SS2022)

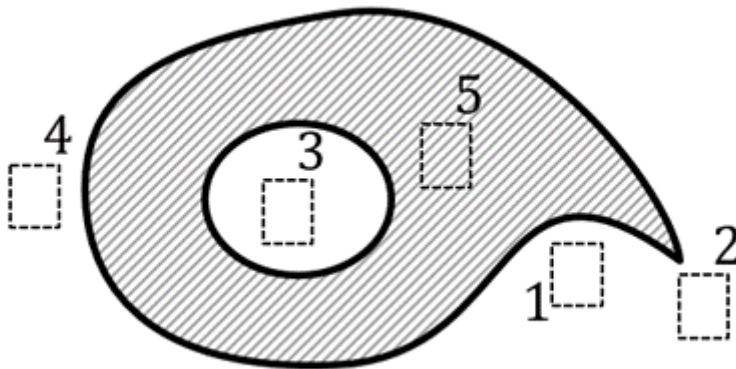
The figure below shows an arrangement of ideal metallic conductors (gray hatched) charged up to $q = +1 \text{ nC}$.

In white a dielectric (e.g. vacuum) is shown.

Several designated areas are shown by dashed frames and numbers x , which are partly inside the object.

Arrange the designated areas clearly according to ascending field strengths $|\vec{E}_x|$ (absolute magnitude)!

Indicate also, if designated areas have quantitatively the same field strength.



Result

$$|E_3| = |E_5| = 0 < |E_1| < |E_4| < |E_2|$$

Exercise E8 Capacitor

(written test, approx. 7 % of a 120-minute written test, SS2022)

Given the parallel plate capacitor shown in the left side of the figure with the following dimensions: $s = 0.1 \text{ mm}$

Result: ϵ_r of air ($\epsilon_r = 1$), while the thickness of the dielectric material

remains the same. Length of layer overlap: $l = 1.5 \text{ mm}$

Path

What is the distance between the plates? $d = 1.0 \text{ mm}$

The dielectric constant is $\epsilon_r = 3$

The number of layers is $N = 10$

Path

For the area A we have multiple plates with the area $A_0 = l \cdot w$ facing each other.

The air between the plates is another capacitor in series to the dielectric material. Therefore, the capacity can be calculated as

$$\frac{1}{C_{\text{Air}}} = \frac{1}{C} + \frac{1}{C_{\text{Air}}}$$

The capacity of air is

$$C_{\text{Air}} = \frac{\epsilon_0 \epsilon_r N l w}{d} = 8.854 \cdot 10^{-12} \cdot 1 \cdot 5 \cdot 1.5 \cdot 10^{-3} \cdot 0.7 \cdot 10^{-3} \cdot 10 \cdot 10^{-6} = 0.465 \text{ nF}$$

The material shall have a dielectric permittivity of $\epsilon_r = 3$.

How many multiple plates N do we have to consider? $N = 10$

For this, we have to count facing areas A_0 . There are $N+1$ faces.

.. What is the field strength in the dielectric material between the layer, when a voltage of $U = 6.3 \text{ V}$ is applied?

Path

The electric field strength E is given by:

$$E = \frac{U}{d} = \frac{6.3 \text{ V}}{1 \cdot 10^{-6} \text{ m}} = 6.3 \cdot 10^6 \text{ V/m}$$

Therefore, the formula is

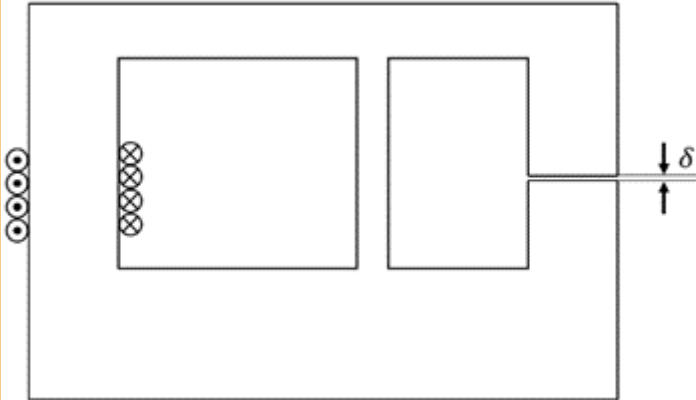
$$C = \frac{\epsilon_0 \epsilon_r N l w}{d} = 8.854 \cdot 10^{-12} \cdot 3 \cdot 5 \cdot 1.5 \cdot 10^{-3} \cdot 0.7 \cdot 10^{-3} \cdot 10 \cdot 10^{-6} = 0.465 \text{ nF}$$

Exercise E10 Magnetic Circuit**(written test, approx. 7 % of a 120-minute written test, SS2022)**

The magnetic setup below shall be given. Draw the equivalent magnetic circuit to represent the setup fully. Name all the necessary magnetic resistances, fluxes, and voltages.

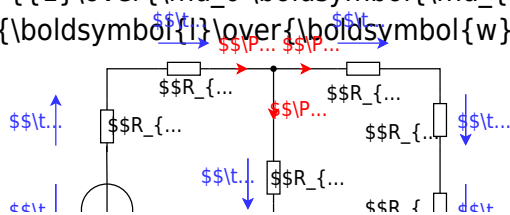
The components shall be designed in such a way, that the magnetic resistance is constant in it.

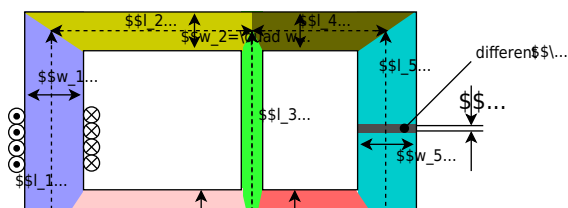
Formulas are not necessary.



Path

Watch for parts of the magnetic circuit, where the width and material are constant. These parts represent the magnetic resistors which have to be calculated individually. Be aware, that every junction creates a branch with a new resistor, like for an electrical circuit - there must be a node on each "diversion".

$$R_{\text{m}} = \frac{1}{\mu_0 \mu_{\text{r}}} \frac{l}{w \cdot h}$$




Full Exam

Here is only a part of the exam in more details given.

The full results can be found in [ILIAS](#)

Full exam

Exercise E2 Electrostatics I

(written test, approx. 10 % of a 120-minute written test, SS2022)

2. What is the magnitude of the electric field E_4 in the picture above? The value of the resulting force of E_4 . Which value needs E_4 to have to get a resulting force of 0 N on q_0 ?

Path: $q_0 = -1 \text{ nC}$

- $q_1 = -2 \text{ nC}$

Path: $E_4 = 2310.97 \text{ V/m}$

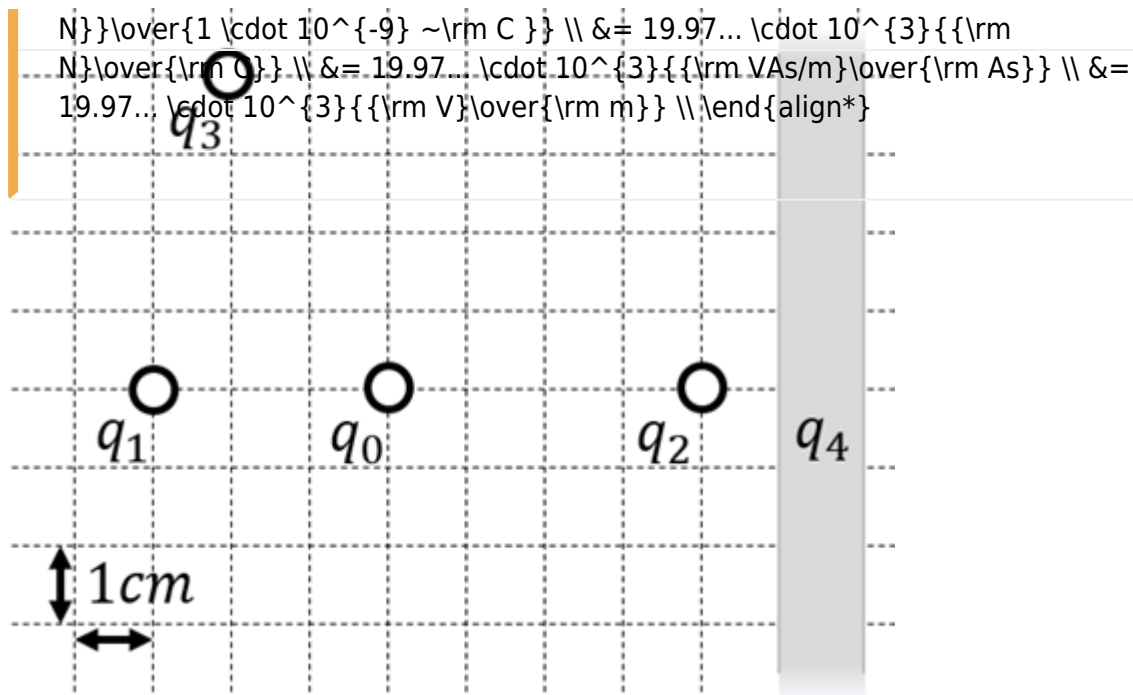
$$\vec{F}_{01} = \left(\begin{array}{c} 19.97 \\ 0 \\ 0 \end{array} \right) \text{ N}$$

With the given data and the composition of the electric field, we can calculate the resulting magnitude

$$F_{01} = \sqrt{F_{01x}^2 + F_{01y}^2 + F_{01z}^2} = \sqrt{19.97^2 + 0^2 + 0^2} = 19.97 \text{ N}$$

Here, this field has to be added to the field E_4 from right to left

$$F_{01} = \sqrt{F_{01x}^2 + F_{01y}^2 + F_{01z}^2} = \sqrt{19.97^2 + 0^2 + 0^2} = 19.97 \text{ N}$$



1. Calculate the single forces $\vec{F}_{01}$, $\vec{F}_{02}$, $\vec{F}_{03}$, on the charge q_0 !

Path

First, calculate the magnitude of the forces, like $\vec{F}_{01}$.

The force $\vec{F}_{01}$ is purely on the x -axis and therefore equal to $F_{01,x}$.
$$\vec{F}_{01} = F_{01,x} = \frac{1}{4\pi\epsilon_0} \cdot \frac{q_1 \cdot q_0}{r_{01}^2} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ As/Vm}} \cdot \frac{1 \cdot 2 \cdot 10^{-9} \text{ C} \cdot 2 \cdot 10^{-9} \text{ C}}{(3 \cdot 10^{-2} \text{ m})^2} = 19.97 \cdot 10^{-6} \text{ Nm} = 19.97 \cdot 10^{-6} \text{ Nm} = 19.97 \cdot 10^{-6} \text{ Nm} = 19.97 \cdot 10^{-6} \text{ Nm} \quad \text{(to the right)}$$

Similarly, we get for $\vec{F}_{02}$ and $\vec{F}_{03}$
$$\vec{F}_{02} = F_{02,x} = -28.09 \cdot 10^{-6} \text{ Nm} \quad \text{(to the right)}$$

$$\vec{F}_{03} = -22.47 \cdot 10^{-6} \text{ Nm} \quad \text{(to the top left)}$$

For $\vec{F}_{03}$, we have to calculate the x - and y -component. This is possible, by using the angle α between the line through q_0 and q_3 and the positive x -axis (pointing to the right).

So, α has to be between 90° and 180° . It can be calculated by:
$$\alpha = \arctan\left(\frac{4 \text{ cm}}{2 \text{ cm}}\right) = \pi - 1.1071 \text{ rad} = 180^\circ - 63.4^\circ = 116.6^\circ$$

Based on this, the x - and y -component is:
$$F_{03,x} =$$

$$\begin{aligned} |\vec{F}_3| \cdot \cos \alpha &= 10.05 \dots \text{ (to the left)} \\ F_{3,y} &= |\vec{F}_3| \cdot \sin \alpha = 20.10 \dots \text{ (to the top)} \end{aligned}$$

[electrical_engineering_and_electronics:task_dtoqvpvrdbdtcozfk_with_calculation](#)
[electrostatic](#), [field lines](#), [exam ee2 ss2022](#)

Exercise E4 Electrostatics II

(written test, approx. 10 % of a 120-minute written test, SS2022)

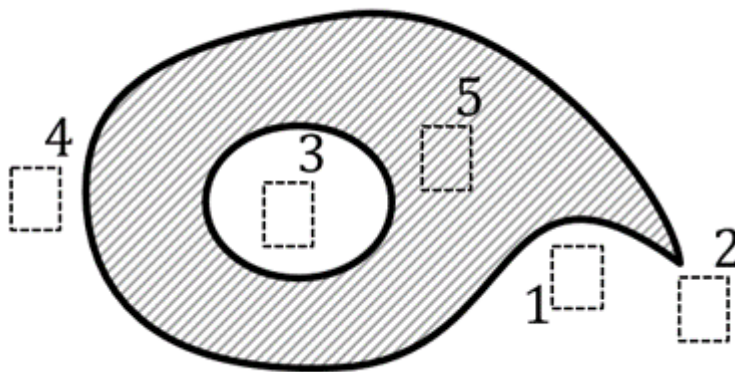
The figure below shows an arrangement of ideal metallic conductors (gray hatched) charged up to $q = +1 \text{ nC}$.

In white a dielectric (e.g. vacuum) is shown.

Several designated areas are shown by dashed frames and numbers x , which are partly inside the object.

Arrange the designated areas clearly according to ascending field strengths $|\vec{E}_x|$ (absolute magnitude)!

Indicate also, if designated areas have quantitatively the same field strength.



Result

$$|E_3| = |E_5| = 0 < |E_1| < |E_4| < |E_2|$$

[electrical_engineering_and_electronics:task_ic9pioiu0notvwfp_with_calculation](#)
[electrostatic](#), [electric field strength](#), [exam ee2 ss2022](#)

Exercise E6 Electron Velocity in Semiconductors

(written test, approx. 6 % of a 120-minute written test, SS2022)

A current of $I = 1 \text{ mA}$ flows through a cross-sectional area $A = 10 \text{ } \mu\text{m}^2$ of a semiconductor.

The electron density in the semiconductor is given by the number of dopant atoms per volume.

The doping shall provide 1 donor atom (= one electron) per 10^{10} silicon atoms. The molar volume of silicon is $V_{\text{mol,Si}} = 12 \cdot 10^{-6} \text{ m}^3/\text{mol}$, with $N_{\text{A}} = 6.022 \cdot 10^{23}$ silicon atoms per 1 mol .

The elementary charge is given as: $e_0 = 1.602 \cdot 10^{-19} \text{ As}$

What is the average electron velocity v_e in this semiconductor?

Path

The following formula gives the speed, where n_e is the number of electrons per volume.
$$v_e = \frac{I}{n_e \cdot e_0 \cdot A}$$

n_e can be derived from the overall number of Si-atoms per volume ($\frac{N_{\text{A}}}{V_{\text{mol,Si}}}$) and the fraction k_{Donators} of these atoms, which got substituted by donors.
$$v_e = \frac{I}{\left(\frac{N_{\text{A}}}{V_{\text{mol,Si}}} \cdot k_{\text{Donators}}\right) \cdot e_0 \cdot A}$$

Putting in the numbers:
$$v_e = \frac{1 \cdot 10^{-3} \text{ A}}{\left(\frac{6.022 \cdot 10^{23}}{12 \cdot 10^{-6} \text{ m}^3/\text{mol}}\right) \cdot 10^{-10} \cdot 1.602 \cdot 10^{-19} \text{ As} \cdot 10 \cdot 10^{-12} \text{ m}^2}$$

[electrical_engineering_and_electronics:task_tx86fewvsrcy8fc_with_calculation](#)
electrostatic, electric field strength, exam ee2 ss2022

Exercise E8 Capacitor

(written test, approx. 7 % of a 120-minute written test, SS2022)

2. Calculate the capacitance of a capacitor with the following dimensions: $\epsilon_{\text{r,c}} = 0.1 \text{ mm}$ of air ($\epsilon_{\text{r,c}} = 1$), while the thickness of the dielectric material is the same: $l = 1.5 \text{ mm}$

Path: Distance between single layers: $d = 1.0 \text{ } \mu\text{m}$

- Depth of component: $w = 0.7 \text{ mm}$

3 layers (from left to right): 3 left-side and 3 right-side layers.

Path

The capacity can be derived from the geometry by:
$$C = \frac{\epsilon_0 \epsilon_r A}{d}$$

The air binds another capacitor in series to the dielectric material. Therefore, the capacity can be calculated as
$$\frac{1}{C_{\text{Air}}} = \frac{1}{C_{\text{dielectric}}} + \frac{1}{C_{\text{air}}}$$

The capacity of air is
$$C_{\text{Air}} = \frac{\epsilon_0 A}{d_{\text{Air}}} = 8.854 \cdot 10^{-12} \frac{\text{As}}{\text{Vm}} \cdot \frac{5 \cdot 1.5 \cdot 10^{-3} \text{ m}}{0.7 \cdot 10^{-3} \text{ m}} = 0.465 \text{ nF}$$

By this the overall capacity
$$C = \frac{1}{\frac{1}{C_{\text{dielectric}}} + \frac{1}{C_{\text{Air}}}} = \frac{1}{\frac{1}{0.139 \text{ nF}} + \frac{1}{0.465 \text{ nF}}} = 0.105 \text{ nF}$$

How many "multiple plates" N do we have to consider?
 .. What is the field strength in the dielectric material between the layer, when a voltage of $U = 6.3 \text{ V}$ is applied?

Path

The electric field strength E is given by:
$$E = \frac{U}{d} = \frac{6.3 \text{ V}}{1 \cdot 10^{-6} \text{ m}} = 6.3 \cdot 10^6 \text{ V/m}$$

Therefore, the formula is
$$C = \frac{\epsilon_0 \epsilon_r N A}{d} = 8.854 \cdot 10^{-12} \frac{\text{As}}{\text{Vm}} \cdot 3 \cdot \frac{5 \cdot 1.5 \cdot 10^{-3} \text{ m}}{1 \cdot 10^{-6} \text{ m}} = 0.199 \text{ nF}$$

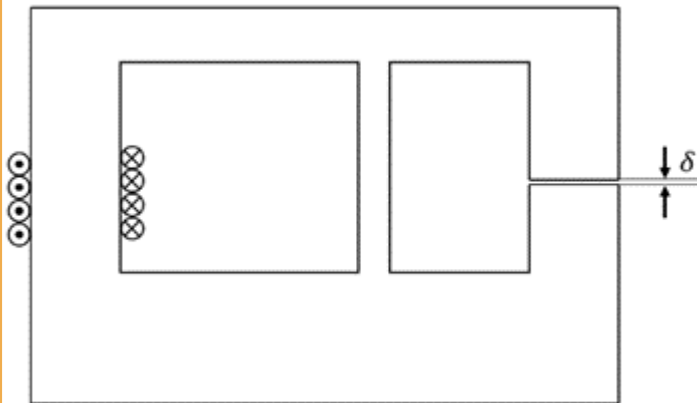
electrostatic, capacitor, plate capacitor, capacity, exam ee2 ss2022

Exercise E10 Magnetic Circuit

(written test, approx. 7 % of a 120-minute written test, SS2022)

The magnetic setup below shall be given. Draw the equivalent magnetic circuit to represent the setup fully. Name all the necessary magnetic resistances, fluxes, and voltages.

The components shall be designed in such a way, that the magnetic resistance is constant in it.
Formulas are not necessary.



Path

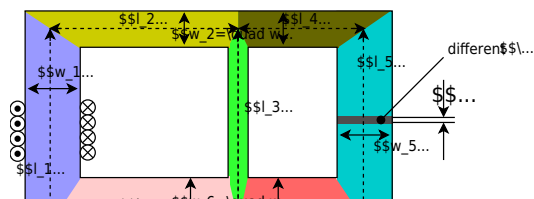
Watch for parts of the magnetic circuit, where the width and material are constant.

These parts represent the magnetic resistors which have to be calculated individually.

Be aware, that every junction creates a branch with a new resistor, like for an electrical circuit - there must be a node on each "diversion".

$$R_{\text{m}} = \frac{l}{\mu_0 \mu_r w h}$$

$$\Phi = \frac{U}{R_{\text{m}}}$$



electrical_engineering_and_electronics:task_yp4rbdlj8kktyrhp_with_calculation
magnetic circuit, exam ee2 ss2022

Exercise E11 Self Induction

(written test, approx. 8 % of a 120-minute written test, SS2022)

2. A motor is connected to a DC voltage source, which is fused with a circuit breaker.

Sketch the diagram of the circuit with the current $i(t)$ and the voltage $u(t)$. The current $i(t)$ is given by the function $i(t) = I_0 \cdot e^{-t/\tau}$ with $I_0 = 10 \text{ A}$ and $\tau = 0.1 \text{ s}$. The inner resistance of the motor shall be neglected.)

The inner resistance of the motor shall be neglected.)

$$u_{\text{ind}}(t) = 3150 \text{ V}$$

Path

.. Draw the circuit (the circuit breaker can be drawn as a switch), with all voltage and current arrows.

For the maximum voltage on the circuit breaker one has to consider the following:

- external voltage of the voltage source U_{ss}
- voltage $u_{\text{ind}}(t)$ induced by the change of the current

The first one is not given in the exercise, and therefore not considered here.

The induced voltage can be calculated by linearizing the following:

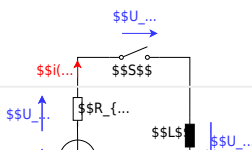
$$u_{\text{ind}}(t) = -L \frac{di(t)}{dt}$$

$$\rightarrow u_{\text{ind}}(t) = -L \frac{\Delta i}{\Delta t}$$

With the given details:

$$u_{\text{ind}}(t) = -L \frac{0 - I}{t_1 - t_0} = 50 \cdot 10^{-6} \cdot \frac{63 \text{ A}}{1 \cdot 10^{-6} \text{ s}} = 3150 \frac{\text{Vs}}{\text{A}} \cdot \frac{\text{A}}{\text{s}} = 3150 \frac{\text{Vs}}{\text{A}} \cdot \frac{\text{A}}{\text{s}}$$

SSU...inSSU...



electrical_engineering_and_electronics:task_unkkahm3u0v9azny_with_calculation
self induction, induction, exam ee2 ss2022

Exercise E13 Series Resonant Circuit

(written test, approx. 10 % of a 120-minute written test, SS2022)

2. What is the resonance frequency of the series RLC circuit shown in the diagram? The circuit parameters are: $R = 10 \text{ } \Omega$, $L = 1 \text{ mH}$, $C = 10 \text{ nF}$. The resonance frequency is the frequency at which the impedance of the circuit is purely resistive.

In this case, the resonance frequency f_0 would be $f_0 = \frac{1}{2\pi\sqrt{LC}}$. Which value would C_0 have for the given f_0 ?

- Path:
- $C = 10 \text{ nF}$
 - $R = 10 \text{ } \Omega$
 - $L = 1 \text{ mH}$
 - $f_0 = 100 \text{ kHz}$

The resonance frequency is given as

$$f_0 = \frac{1}{2\pi\sqrt{LC}}$$

The calculation for C_0 is:

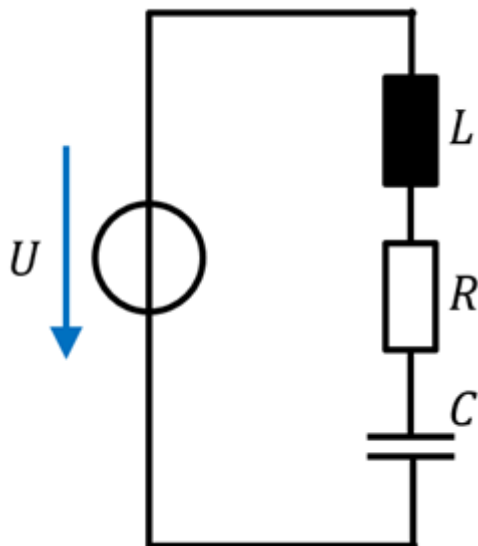
$$C_0 = \frac{1}{4\pi^2 f_0^2 L}$$

At resonance, the impedance is given by the resistor

$$Z_{\text{RLC}} = R$$

With values:

$$C = \frac{1}{4\pi^2 (100 \cdot 10^3)^2 \cdot 1 \cdot 10^{-3}} = 0.1500 \text{ nF}$$



1. What is the impedance $\underline{Z}_{\text{RLC}}$ of this real capacitor for $f_0 = 100 \text{ MHz}$? (Phase and magnitude)

Path

The impedance $\underline{Z}_{\text{RLC}}$ is given by:
$$\underline{Z}_{\text{RLC}} = R + \underline{X}_L + \underline{X}_C \quad \Leftrightarrow R + j\omega L - \frac{j}{\omega C} \quad \Leftrightarrow R + j\left(\omega L - \frac{1}{\omega C}\right) \quad \Leftrightarrow R + jX_{\text{LC}}$$

Putting in the numbers, only for the reactive part X_{LC} :
$$X_{\text{LC}} = 2\pi \cdot f_0 \cdot L - \frac{1}{2\pi \cdot f_0 \cdot C} \quad \Leftrightarrow 2\pi \cdot 100 \cdot 10^6 \text{ Hz} \cdot 60 \cdot 10^{-12} \text{ H} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \text{ Hz} \cdot 10 \cdot 10^{-9} \text{ F}} \quad \Leftrightarrow -121.45 \text{ m}\Omega$$

With the real and imaginary parts, we can derive the magnitude and phase:
$$Z_{\text{RLC}} = \sqrt{R^2 + X_{\text{LC}}^2} \quad \Leftrightarrow \sqrt{(88 \text{ m}\Omega)^2 + (-121.45 \text{ m}\Omega)^2} \quad \Leftrightarrow 150.0 \text{ m}\Omega$$

$$\varphi = \arctan\left(\frac{X_{\text{LC}}}{R}\right) \quad \Leftrightarrow \arctan\left(\frac{-121.45 \text{ m}\Omega}{88 \text{ m}\Omega}\right) \quad \Leftrightarrow -0.9437 \text{ rad} = -54.07^\circ$$

electrical_engineering_and_electronics:task_7el8zljglaazxtw_with_calculation
resonant circuit, exam ee2 ss2022

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Last update: **2026/01/12 00:40**

